# SONY

ICX258AL

Diagonal 6mm (Type 1/3) CCD Image Sensor for EIA B/W Video Cameras

Description

The ICX258AL is an interline CCD solid-state image sensor suitable for EIA B/W video cameras with a diagonal 6mm (Type 1/3) system. Compared with the current product ICX058CL, basic characteristics such as sensitivity, smear, dynamic range and S/N are improved drastically from visible light region to near infrared light region through the adoption of EXview HAD CCD™ technology.

This chip features a field period readout system and an electronic shutter with variable charge-storage time.

16 pin DIP (Plastic)
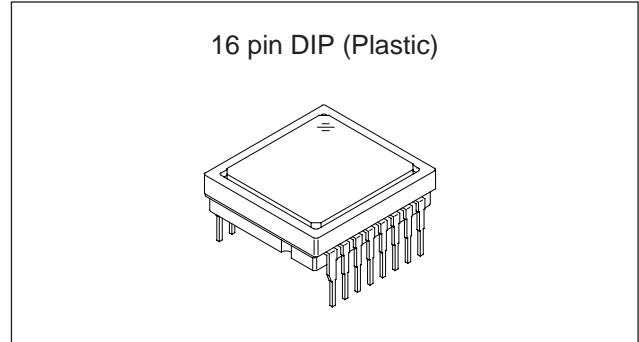
Features

- Sensitivity in near infrared light region
  (+8dB compared with the ICX058CL, λ = 945nm)
- High sensitivity (+7dB compared with the ICX058CL, no IR cut filter)
- Low smear (–20dB compared with the ICX058CL)
- High D range (+4dB compared with the ICX058CL)
- High S/N
- High resolution and low dark current
- Excellent antiblooming characteristics
- Continuous variable-speed shutter
- No voltage adjustment
  (Reset gate and substrate bias are not adjusted.)
- Reset gate: 5V drive
- Horizontal register: 5V drive
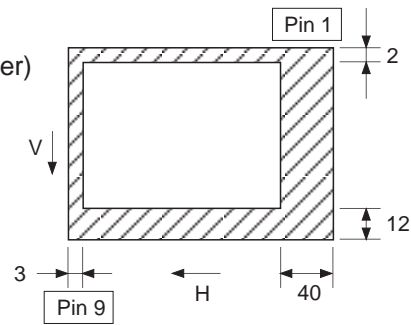
Optical black position
(Top View)

Pin 1
Pin 9
V
H
2
12
3
40

Device Structure

- Interline CCD image sensor
- Image size: Diagonal 6mm (Type 1/3)
- Number of effective pixels: 768 (H) × 494 (V) approx. 380K pixels
- Total number of pixels: 811 (H) × 508 (V) approx. 410K pixels
- Chip size: 6.00mm (H) × 4.96mm (V)
- Unit cell size: 6.35μm (H) × 7.40μm (V)
- Optical black: Horizontal (H) direction : Front 3 pixels, rear 40 pixels
                                            Vertical (V) direction   : Front 12 pixels, rear 2 pixels
- Number of dummy bits: Horizontal 22
                                            Vertical 1 (even fields only)
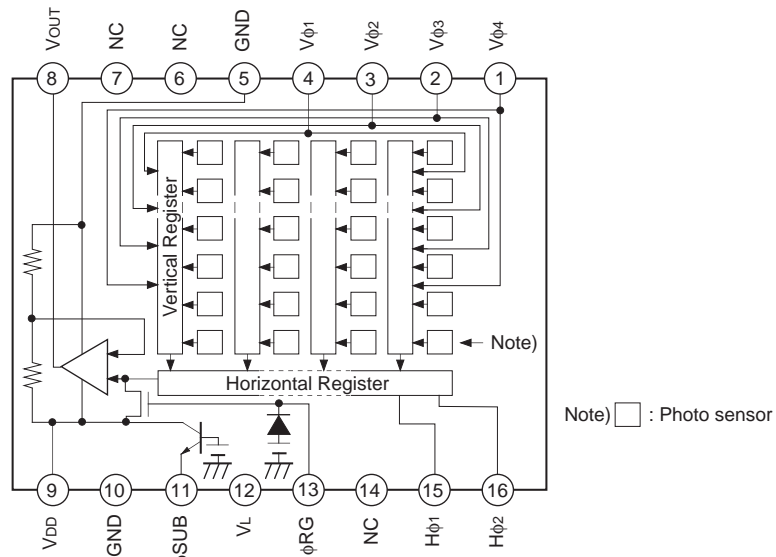- Substrate material: Silicon

EXview HAD CCD ™

E99524A99

**Block Diagram and
Pin Configuration**
(Top View)

Note) ☐ : Photo sensor

Pin Description

Pin No.	Symbol	Description	Pin No.	Symbol	Description
1	Vϕ4	Vertical register transfer clock	9	V$_{DD}$	Supply voltage
2	Vϕ3	Vertical register transfer clock	10	GND	GND
3	Vϕ2	Vertical register transfer clock	11	ϕSUB	Substrate clock
4	Vϕ1	Vertical register transfer clock	12	V$_L$	Protective transistor bias
5	GND	GND	13	ϕRG	Reset gate clock
6	NC		14	NC	
7	NC		15	Hϕ1	Horizontal register transfer clock
8	V$_{OUT}$	Signal output	16	Hϕ2	Horizontal register transfer clock

Absolute Maximum Ratings

Item		Ratings	Unit	Remarks
Against ϕSUB	V$_{DD}$, V$_{OUT}$, ϕRG – ϕSUB	−40 to +8	V	
	Vϕ1, Vϕ3 – ϕSUB	−50 to +15	V	
	Vϕ2, Vϕ4, V$_L$ – ϕSUB	−50 to +0.3	V	
	Hϕ1, Hϕ2, GND – ϕSUB	−40 to +0.3	V	
Against GND	V$_{DD}$, V$_{OUT}$, ϕRG – GND	−0.3 to +20	V	
	Vϕ1, Vϕ2, Vϕ3, Vϕ4 – GND	−10 to +18	V	
	Hϕ1, Hϕ2 – GND	−10 to +6	V	
Against V$_L$	Vϕ1, Vϕ3 – V$_L$	−0.3 to +28	V	
	Vϕ2, Vϕ4, Hϕ1, Hϕ2, GND – V$_L$	−0.3 to +15	V	
Between input clock pins	Voltage difference between vertical clock input pins	to +15	V	[1]
	Hϕ1 – Hϕ2	−6 to +6	V	
	Hϕ1, Hϕ2 – Vϕ4	−14 to +14	V	
Storage temperature		−30 to +80	°C	
Operating temperature		−10 to +60	°C	

[1] +24V (Max.) when clock width < 10μs, clock duty factor < 0.1%.

Bias Conditions

Item	Symbol	Min.	Typ.	Max.	Unit	Remarks
Supply voltage	V_{DD}	14.55	15.0	15.45	V	
Protective transistor bias	V_L		*1			
Substrate clock	ϕSUB		*2			
Reset gate clock	ϕRG		*2			

*1 V_L setting is the V_{VL} voltage of the vertical transfer clock waveform, or the same power supply as the V_L power supply for the V driver should be used.

*2 Do not apply a DC bias to the substrate clock and reset gate clock pins, because a DC bias is generated within the CCD.

DC Characteristics

Item	Symbol	Min.	Typ.	Max.	Unit	Remarks
Supply current	I_{DD}		4	6	mA	

Clock Voltage Conditions

Item	Symbol	Min.	Typ.	Max.	Unit	Waveform diagram	Remarks
Readout clock voltage	V_{VT}	14.55	15.0	15.45	V	1	
Vertical transfer clock voltage	V_{VH1}, V_{VH2}	−0.05	0	0.05	V	2	$V_{VH} = (V_{VH1} + V_{VH2})/2$
	V_{VH3}, V_{VH4}	−0.2	0	0.05	V	2	
	V_{VL1}, V_{VL2}, V_{VL3}, V_{VL4}	−8.0	−7.0	−6.5	V	2	$V_{VL} = (V_{VL3} + V_{VL4})/2$
	$V\phi V$	6.3	7.0	8.05	V	2	$V\phi V = V_{VHn} - V_{VLn}$ (n = 1 to 4)
	$V_{VH3} - V_{VH}$	−0.25		0.1	V	2	
	$V_{VH4} - V_{VH}$	−0.25		0.1	V	2	
	V_{VHH}			0.3	V	2	High-level coupling
	V_{VHL}			0.3	V	2	High-level coupling
	V_{VLH}			0.3	V	2	Low-level coupling
	V_{VLL}			0.3	V	2	Low-level coupling
Horizontal transfer clock voltage	$V\phi H$	4.75	5.0	5.25	V	3	
	V_{HL}	−0.05	0	0.05	V	3	
Reset gate clock voltage	$V\phi RG$	4.5	5.0	5.5	V	4	Input through 0.1μF capacitance
	$V_{RGLH} - V_{RGLL}$			0.4	V	4	Low-level coupling
	$V_{RGL} - V_{RGLm}$			0.5	V	4	Low-level coupling
Substrate clock voltage	$V\phi SUB$	21.0	22.0	23.5	V	5	

Clock Equivalent Circuit Constant

Item	Symbol	Min.	Typ.	Max.	Unit	Remarks
Capacitance between vertical transfer clock and GND	$C\phi V_1$, $C\phi V_3$		1200		pF	
	$C\phi V_2$, $C\phi V_4$		1000		pF	
Capacitance between vertical transfer clocks	$C\phi V_{12}$, $C\phi V_{34}$		820		pF	
	$C\phi V_{23}$, $C\phi V_{41}$		330		pF	
	$C\phi V_{13}$		100		pF	
	$C\phi V_{24}$		100		pF	
Capacitance between horizontal transfer clock and GND	$C\phi H_1$, $C\phi H_2$		75		pF	
Capacitance between horizontal transfer clocks	$C\phi HH$		22		pF	
Capacitance between reset gate clock and GND	$C\phi RG$		5		pF	
Capacitance between substrate clock and GND	$C\phi SUB$		270		pF	
Vertical transfer clock series resistor	R_1, R_3		82		Ω	
	R_2, R_4		120		Ω	
Vertical transfer clock ground resistor	R_{GND}		100		Ω	
Horizontal transfer clock series resistor	$R\phi H$		15		Ω	
Reset gate clock series resistor	$R\phi RG$		50		Ω	
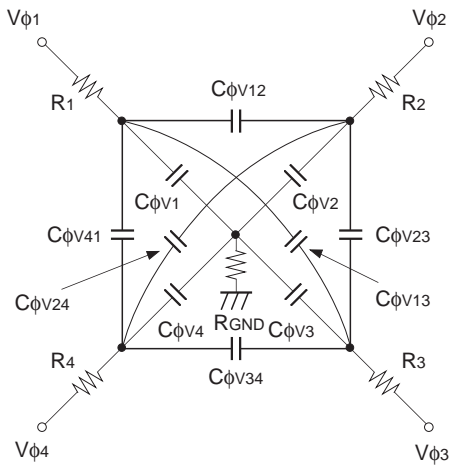
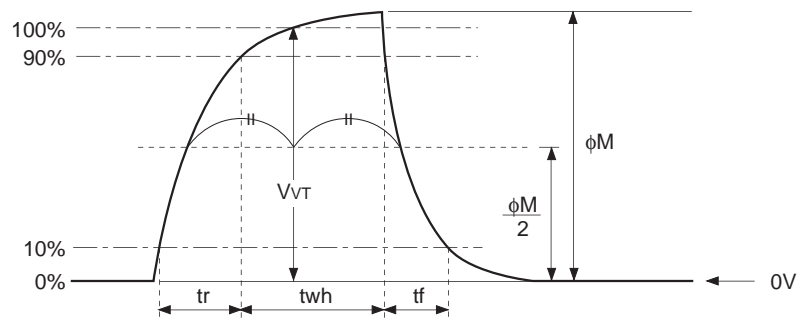

Vertical transfer clock equivalent circuit
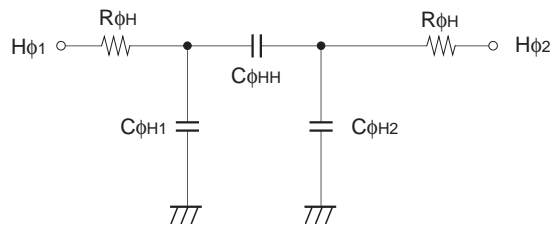
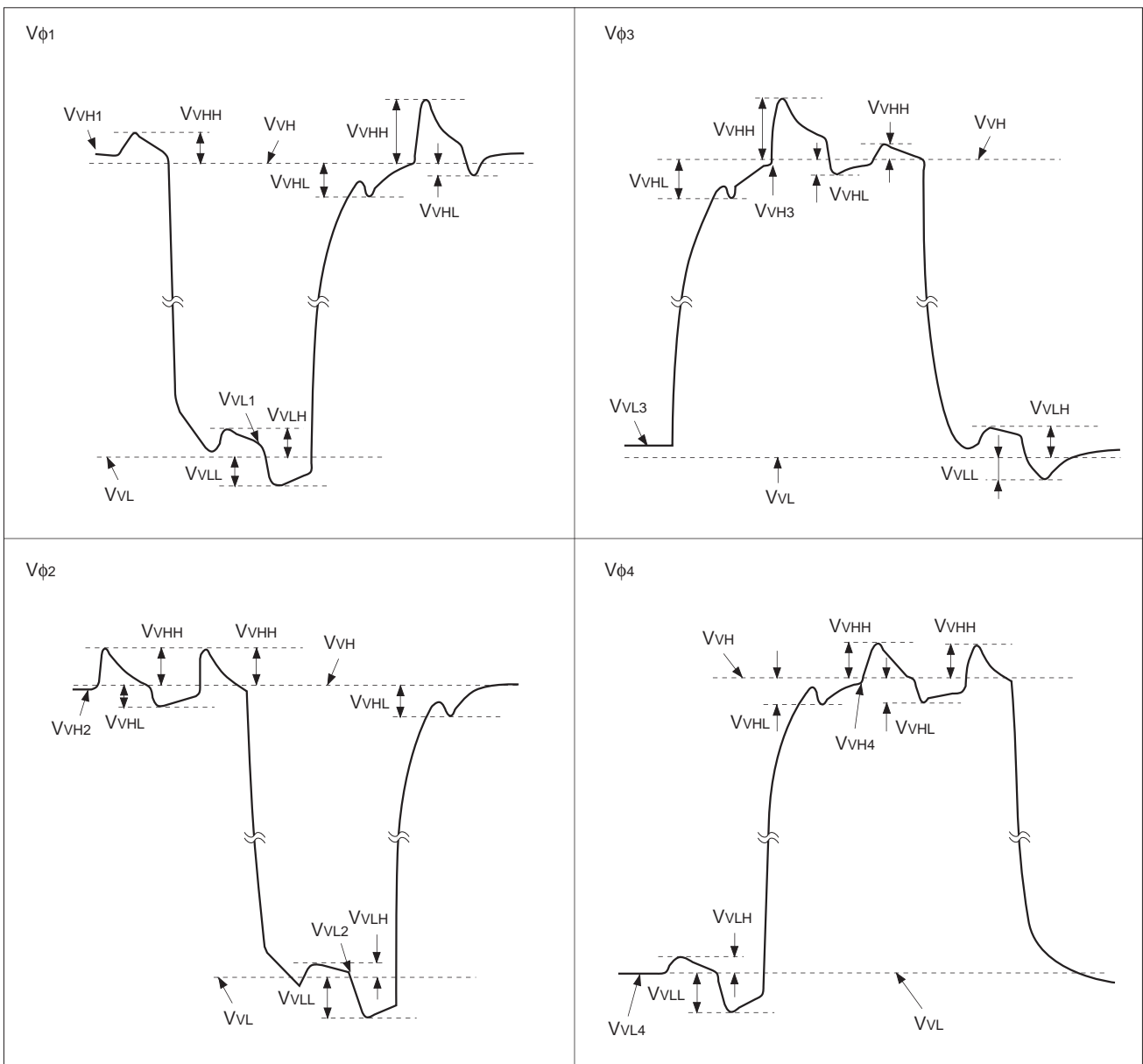**Horizontal transfer clock equivalent circuit**
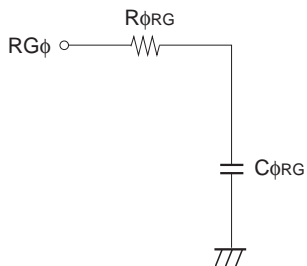
Reset gate clock equivalent circuit

Drive Clock Waveform Conditions

(1) Readout clock waveform

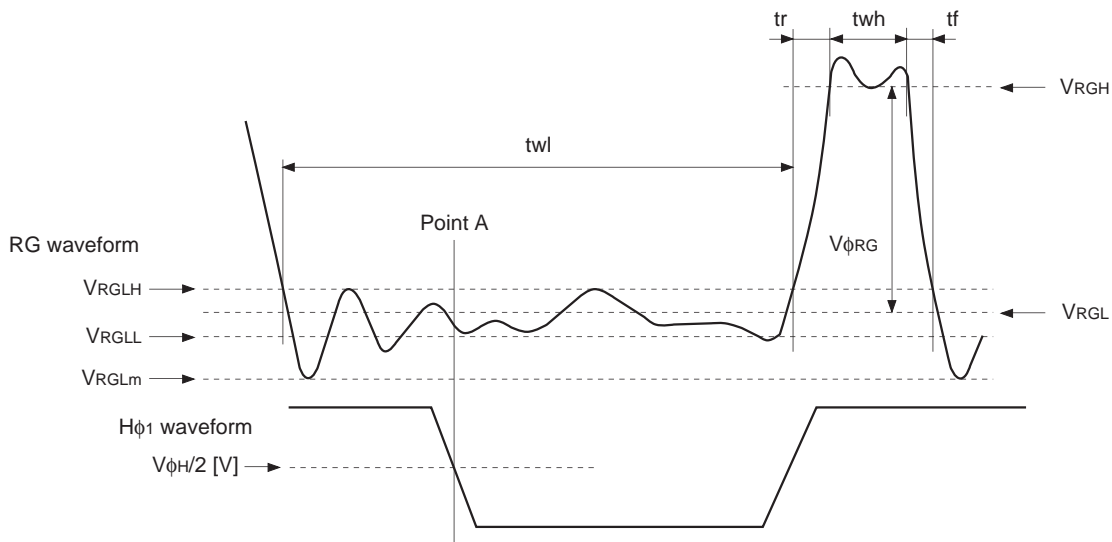### (2) Vertical transfer clock waveform

$V_{VH} = (V_{VH1} + V_{VH2})/2$

$V_{VL} = (V_{VL3} + V_{VL4})/2$

$V\phi_V = V_{VHn} - V_{VLn}$ (n = 1 to 4)

– 5 –

(3) Horizontal transfer clock waveform

(4) Reset gate clock waveform

V_{RGLH} is the maximum value and V_{RGLL} is the minimum value of the coupling waveform during the period from Point A in the above diagram until the rising edge of RG. In addition, V_{RGL} is the average value of V_{RGLH} and V_{RGLL}.
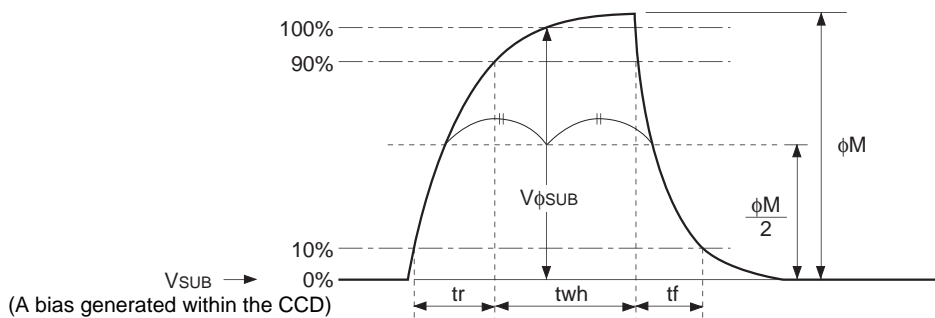
$$V_{RGL} = (V_{RGLH} + V_{RGLL})/2$$

Assuming V_{RGH} is the minimum value during the interval twh, then:

$$V\phi_{RG} = V_{RGH} - V_{RGL}$$

Negative overshoot level during the falling edge of RG is V_{RGLm}.

(5) Substrate clock waveform

Clock Switching Characteristics

Item	Symbol	twh Min.	twh Typ.	twh Max.	twl Min.	twl Typ.	twl Max.	tr Min.	tr Typ.	tr Max.	tf Min.	tf Typ.	tf Max.	Unit	Remarks
Readout clock	V_T	2.3	2.5						0.5			0.5		µs	During readout
Vertical transfer clock	$V\phi_1, V\phi_2, V\phi_3, V\phi_4$										15		250	ns	*1
Horizontal transfer clock — During imaging — $H\phi_1$	$H\phi_1$	26	28.5		26	28.5			6.5	9.5		6.5	9.5	ns	*2
Horizontal transfer clock — During imaging — $H\phi_2$	$H\phi_2$	26	28.5		26	28.5			6.5	9.5		6.5	9.5	ns	*2
Horizontal transfer clock — During parallel-serial conversion — $H\phi_1$	$H\phi_1$		5.38						0.01			0.01		µs	
Horizontal transfer clock — During parallel-serial conversion — $H\phi_2$	$H\phi_2$					5.38			0.01			0.01		µs	
Reset gate clock	ϕRG	11	13			51			3			3		ns	
Substrate clock	ϕSUB	1.5	1.8						0.5			0.5		µs	During drain charge

*1 When vertical transfer clock driver CXD1267AN is used.

*2 $tf \geq tr - 2ns$, and the cross-point voltage (V_{CR}) for the $H\phi_1$ rising side of the $H\phi_1$ and $H\phi_2$ waveforms must be at least $V\phi_H/2$ [V].

Item	Symbol	two Min.	two Typ.	two Max.	Unit	Remarks
Horizontal transfer clock	$H\phi_1, H\phi_2$	22	26		ns	*3

*3 The overlap period for twh and twl of horizontal transfer clocks $H\phi_1$ and $H\phi_2$ is two.

Image Sensor Characteristics (Ta = 25°C)

Item	Symbol	Min.	Typ.	Max.	Unit	Measurement method	Remarks
Sensitivity 1	S1	720	1000		mV	1	
Sensitivity 2	S2	2200	3200		mV	2	
Saturation signal	Vsat	1000			mV	3	Ta = 60°C
Smear	Sm		−115	−98	dB	4	
Video signal shading	SH			20	%	5	Zone 0 and I
				25	%	5	Zone 0 to II'
Dark signal	Vdt			2	mV	6	Ta = 60°C
Dark signal shading	ΔVdt			1	mV	7	Ta = 60°C
Flicker	F			2	%	8	
Lag	Lag			0.5	%	9	

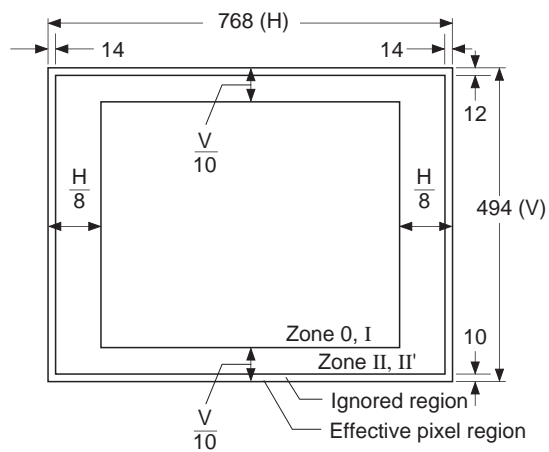**Zone Definition of Video Signal Shading**

Image Sensor Characteristics Measurement Method

◎ **Measurement conditions**

1) In the following measurements, the device drive conditions are at the typical values of the bias and clock voltage conditions.

2) In the following measurements, spot blemishes are excluded and, unless otherwise specified, the optical black (OB) level is used as the reference for the signal output, and the value measured at point [∗A] in the drive circuit example is used.

◎ **Definition of standard imaging conditions**

1) Standard imaging condition I:
   Use a pattern box (luminance: 706cd/m^2, color temperature of 3200K halogen source) as a subject. (Pattern for evaluation is not applicable.) Use a testing standard lens with CM500S (t = 1.0mm) as an IR cut filter and image at F8. The luminous intensity to the sensor receiving surface at this point is defined as the standard sensitivity testing luminous intensity.

2) Standard imaging condition II:
   Indicate the state which removes an IR cut filter of standard imaging condition I.

3) Standard imaging condition III:
   Image a light source (color temperature of 3200K) with a uniformity of brightness within 2% at all angles. Use a testing standard lens with CM500S (t = 1.0mm) as an IR cut filter. The luminous intensity is adjusted to the value indicated in each testing item by the lens diaphragm.

1. Sensitivity 1
   Set to standard imaging condition I. After selecting the electronic shutter mode with a shutter speed of 1/250s, measure the signal output (Vs_1) at the center of the screen and substitute the value into the following formula.

   $$S1 = Vs_1 \times \frac{250}{60} \ [mV]$$

2. Sensitivity 2
   Set to standard imaging condition II. After selecting the electronic shutter mode with a shutter speed of 1/1000s, measure the signal output (Vs_2) at the center of the screen and substitute the value into the following formula.

   $$S2 = Vs_2 \times \frac{1000}{60} \ [mV]$$

3. Saturation signal
   Set to standard imaging condition III. After adjusting the luminous intensity to 10 times the intensity with the average value of the signal output, 200mV, measure the minimum value of the signal output.

4. Smear
   Set to standard imaging condition III. With the lens diaphragm at F5.6 to F8, adjust the luminous intensity to 500 times the intensity with average value of the signal output, 200mV. When the readout clock is stopped and the charge drain is executed by the electronic shutter at the respective H blankings, measure the maximum value YSm [mV] of the signal output and substitute the value into the following formula.

   $$Sm = 20 \times \log \left(\frac{VSm}{200} \times \frac{1}{500} \times \frac{1}{10} \right) \ [dB] \ (1/10V \ method \ conversion \ value)$$

5. Video signal shading

Set to standard imaging condition III. With the lens diaphragm at F5.6 to F8, adjust the luminous intensity so that the average value of the signal output is 200mV. Then measure the maximum (Vmax [mV]) and minimum (Vmin [mV]) values of the signal output and substitute the values into the following formula.

$$SH = (Vmax - Vmin)/200 \times 100 \, [\%]$$

6. Dark signal

Measure the average value of the signal output (Vdt [mV]) with the device ambient temperature 60°C and the device in the light-obstructed state, using the horizontal idle transfer level as a reference.

7. Dark signal shading

After measuring 6, measure the maximum (Vdmax [mV]) and minimum (Vdmin [mV]) values of the dark signal output and substitute the values into the following formula.

$$\Delta Vdt = Vdmax - Vdmin \, [mV]$$

8. Flicker

Set to standard imaging condition III. Adjust the luminous intensity so that the average value of the signal output is 200mV, and then measure the difference in the signal level between fields (ΔVf [mV]). Then substitute the value into the following formula.

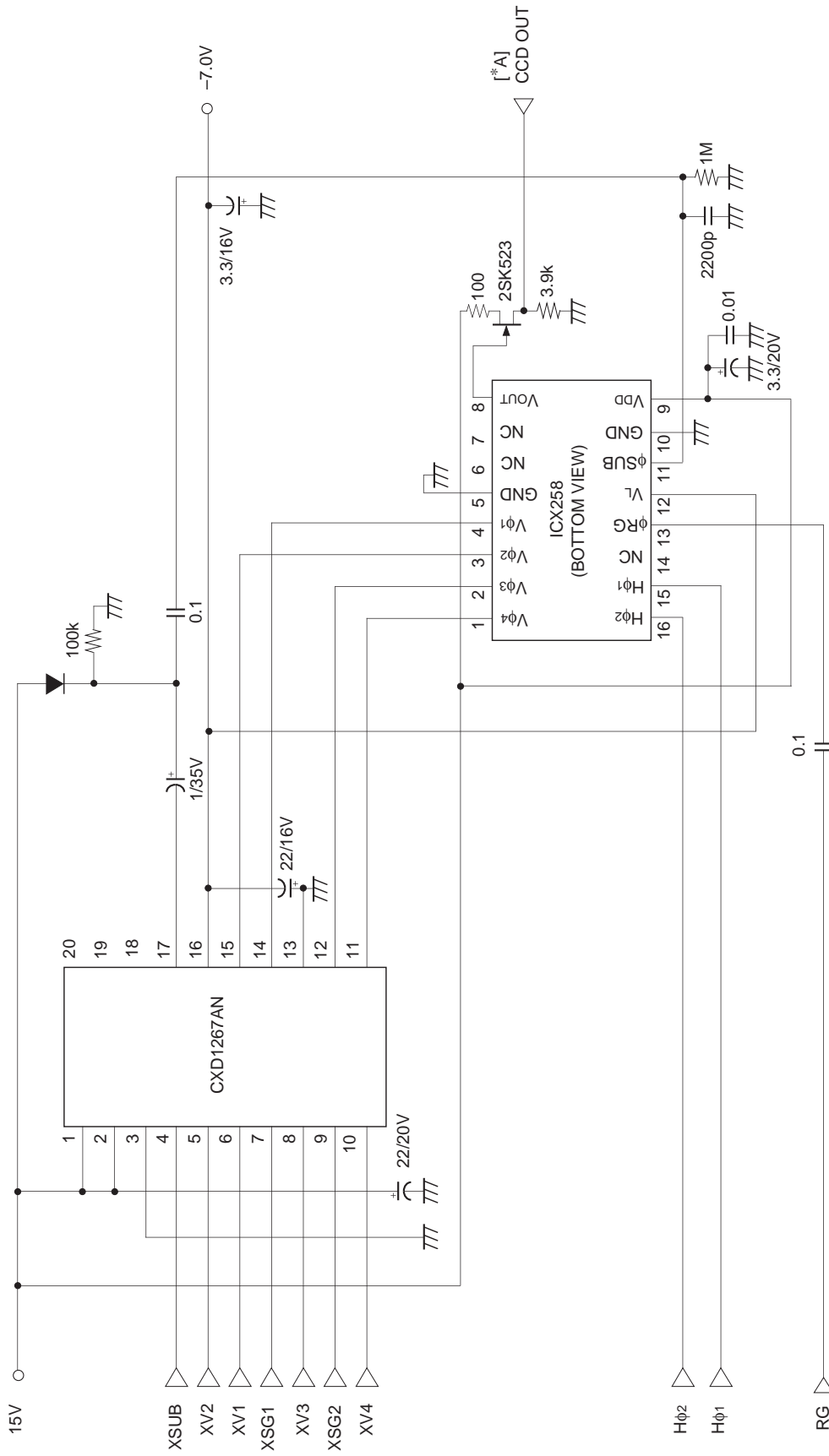$$F = (\Delta Vf/200) \times 100 \, [\%]$$

9. Lag

Adjust the signal output value generated by strobe light to 200mV. After setting the strobe light so that it strobes with the following timing, measure the residual signal (Vlag). Substitute the value into the following formula.
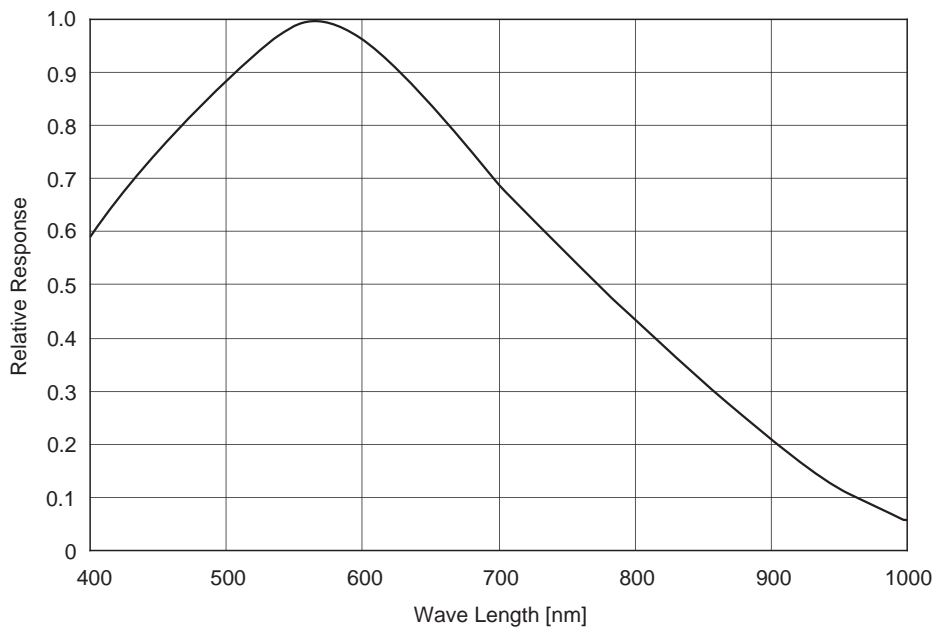
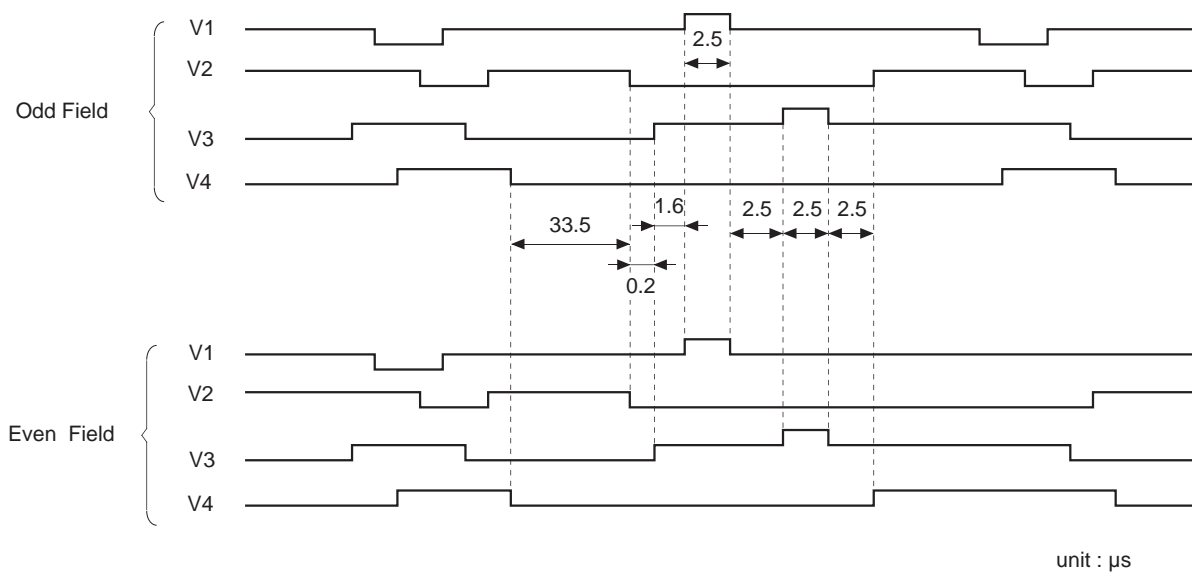$$Lag = (Vlag/200) \times 100 \, [\%]$$
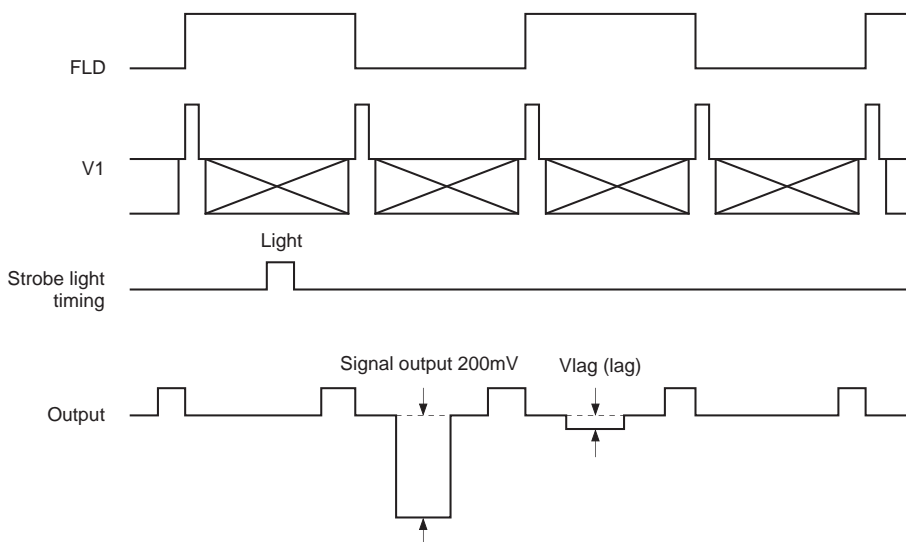
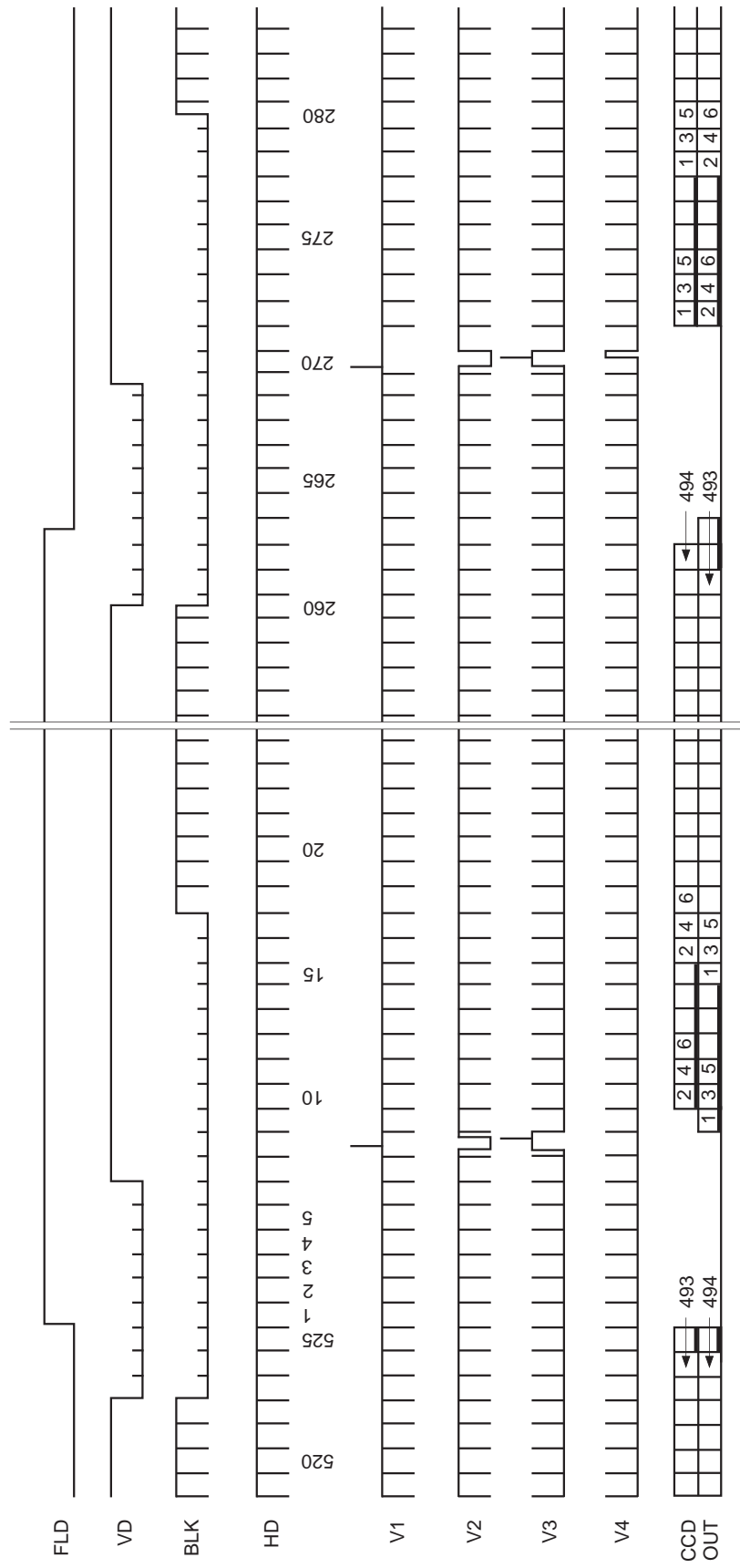**Drive Circuit**

Spectral Sensitivity Characteristics

(excludes both lens characteristics and light source characteristics)

Sensor Readout Clock Timing Chart
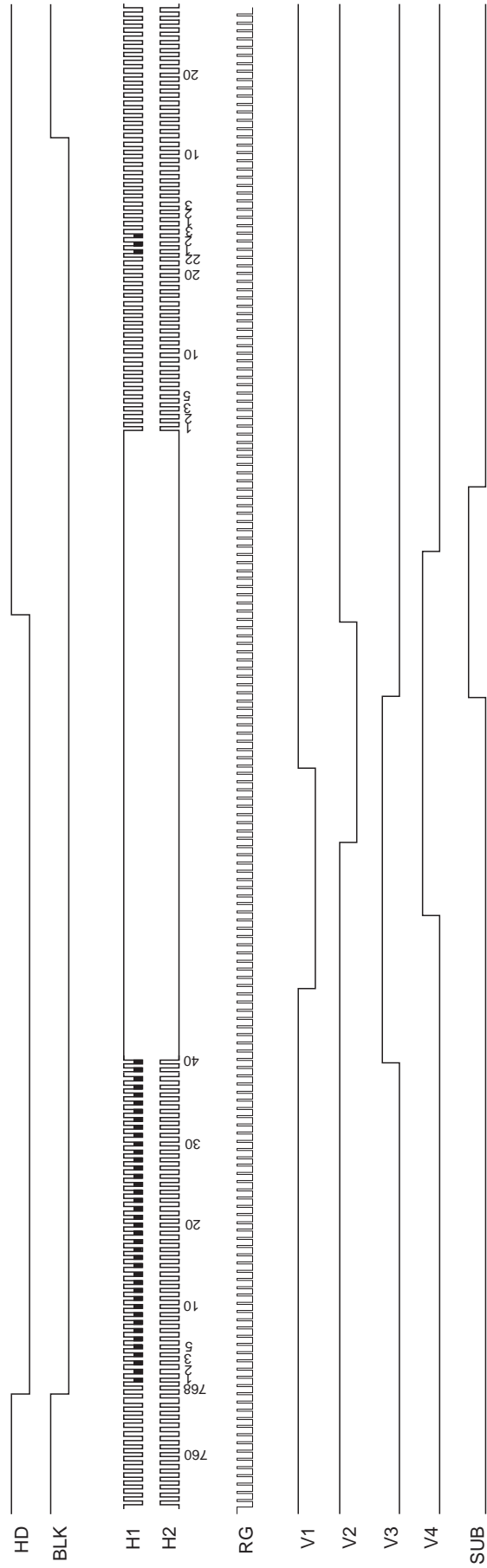

unit : µs

Drive Timing Chart (Vertical Sync)

Drive Timing Chart (Horizontal Sync)

HD	
BLK	
H1	
H2	
RG	
V1	
V2	
V3	
V4	
SUB	

Notes on Handling

1) Static charge prevention

CCD image sensors are easily damaged by static discharge. Before handling be sure to take the following protective measures.

a) Either handle bare handed or use non-chargeable gloves, clothes or material.

Also use conductive shoes.

b) When handling directly use an earth band.

c) Install a conductive mat on the floor or working table to prevent the generation of static electricity.

d) Ionized air is recommended for discharge when handling CCD image sensor.

e) For the shipment of mounted substrates, use boxes treated for the prevention of static charges.

2) Soldering

a) Make sure the package temperature does not exceed 80°C.

b) Solder dipping in a mounting furnace causes damage to the glass and other defects. Use a ground 30W soldering iron and solder each pin in less than 2 seconds. For repairs and remount, cool sufficiently.

c) To dismount an image sensor, do not use a solder suction equipment. When using an electric desoldering tool, use a thermal controller of the zero cross On/Off type and connect it to ground.

3) Dust and dirt protection

Image sensors are packed and delivered by taking care of protecting its glass plates from harmful dust and dirt. Clean glass plates with the following operation as required, and use them.

a) Perform all assembly operations in a clean room (class 1000 or less).

b) Do not either touch glass plates by hand or have any object come in contact with glass surfaces. Should dirt stick to a glass surface, blow it off with an air blower. (For dirt stuck through static electricity ionized air is recommended.)

c) Clean with a cotton bud and ethyl alcohol if the grease stained. Be careful not to scratch the glass.

d) Keep in a case to protect from dust and dirt. To prevent dew condensation, preheat or precool when moving to a room with great temperature differences.

e) When a protective tape is applied before shipping, just before use remove the tape applied for electrostatic protection. Do not reuse the tape.

4) Installing (attaching)

a) Remain within the following limits when applying a static load to the package. Do not apply any load more than 0.7mm inside the outer perimeter of the glass portion, and do not apply any load or impact to limited portions. (This may cause cracks in the package.)
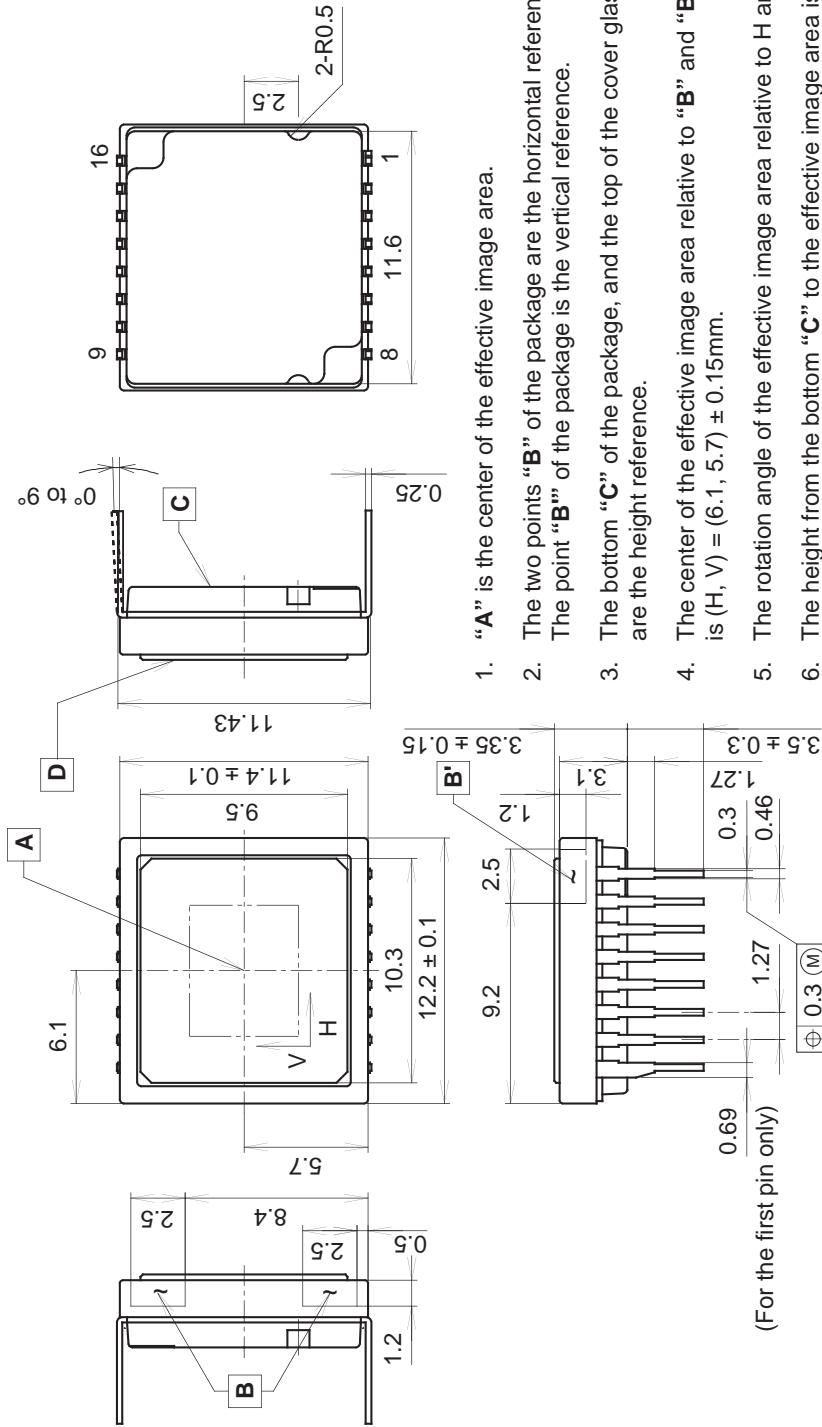
Cover glass

Plastic package 50N 50N 1.2Nm

Compressive strength **Torsional strength**
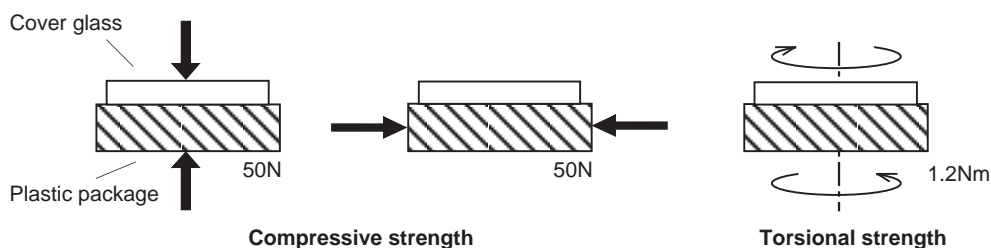
b) If a load is applied to the entire surface by a hard component, bending stress may be generated and the package may fracture, etc., depending on the flatness of the bottom of the package. Therefore, for installation, use either an elastic load, such as a spring plate, or an adhesive.

c) The adhesive may cause the marking on the rear surface to disappear, especially in case the regulated voltage value is indicated on the rear surface. Therefore, the adhesive should not be applied to this area, and indicated values should be transferred to the other locations as a precaution.

d) The notch of the package is used for directional index, and that can not be used for reference of fixing.
   In addition, the cover glass and seal resin may overlap with the notch of the package.

e) If the lead bend repeatedly and the metal, etc., clash or rub against the package, the dust may be generated by the fragments of resin.

f) Acrylate anaerobic adhesives are generally used to attach CCD image sensors. In addition, cyano-acrylate instantaneous adhesives are sometimes used jointly with acrylate anaerobic adhesives. (reference)

5) Others

a) Do not expose to strong light (sun rays) for long periods. For continuous using under cruel condition exceeding the normal using condition, consult our company.

b) Exposure to high temperature or humidity will affect the characteristics. Accordingly avoid storage or usage in such conditions.

c) The brown stain may be seen on the bottom or side of the package. But this does not affect the CCD characteristics.

d) This CCD image sensor has sensitivity in the near infrared area. Its focus may not match in the same condition under visible light /near infrared light because of aberration. Incident light component of long wavelength which transmits the silicon substrate may have bad influence upon image.

Package Outline   Unit: mm

16pin DIP (450mil)

1. "**A**" is the center of the effective image area.

2. The two points "**B**" of the package are the horizontal reference.
    The point "**B'**" of the package is the vertical reference.

3. The bottom "**C**" of the package, and the top of the cover glass "**D**" are the height reference.

4. The center of the effective image area relative to "**B**" and "**B'''**" is (H, V) = (6.1, 5.7) ± 0.15mm.

5. The rotation angle of the effective image area relative to H and V is ± 1°.

6. The height from the bottom "**C**" to the effective image area is 1.41 ± 0.10mm.
    The height from the top of the cover glass "**D**" to the effective image area is 1.94 ± 0.15mm.

7. The tilt of the effective image area relative to the bottom "**C**" is less than 50μm.
    The tilt of the effective image area relative to the top "**D**" of the cover glass is less than 50μm.

8. The thickness of the cover glass is 0.75mm, and the refractive index is 1.5.

9. The notches on the bottom of the package are used only for directional index, they must not be used for reference of fixing.

PACKAGE STRUCTURE

PACKAGE MATERIAL	Plastic
LEAD TREATMENT	GOLD PLATING
LEAD MATERIAL	42 ALLOY
PACKAGE WEIGHT	0.9g